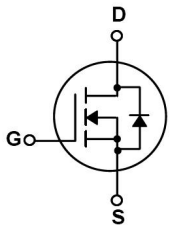
TO-262 N MOS N-CHANNEL MOSFET in a TO-262 Plastic Package.

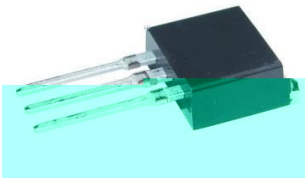
, ,

Low gate charge, low crss, fast switching.

DC/DC

These devices are well suited for high efficiency switching DC/DC converters .

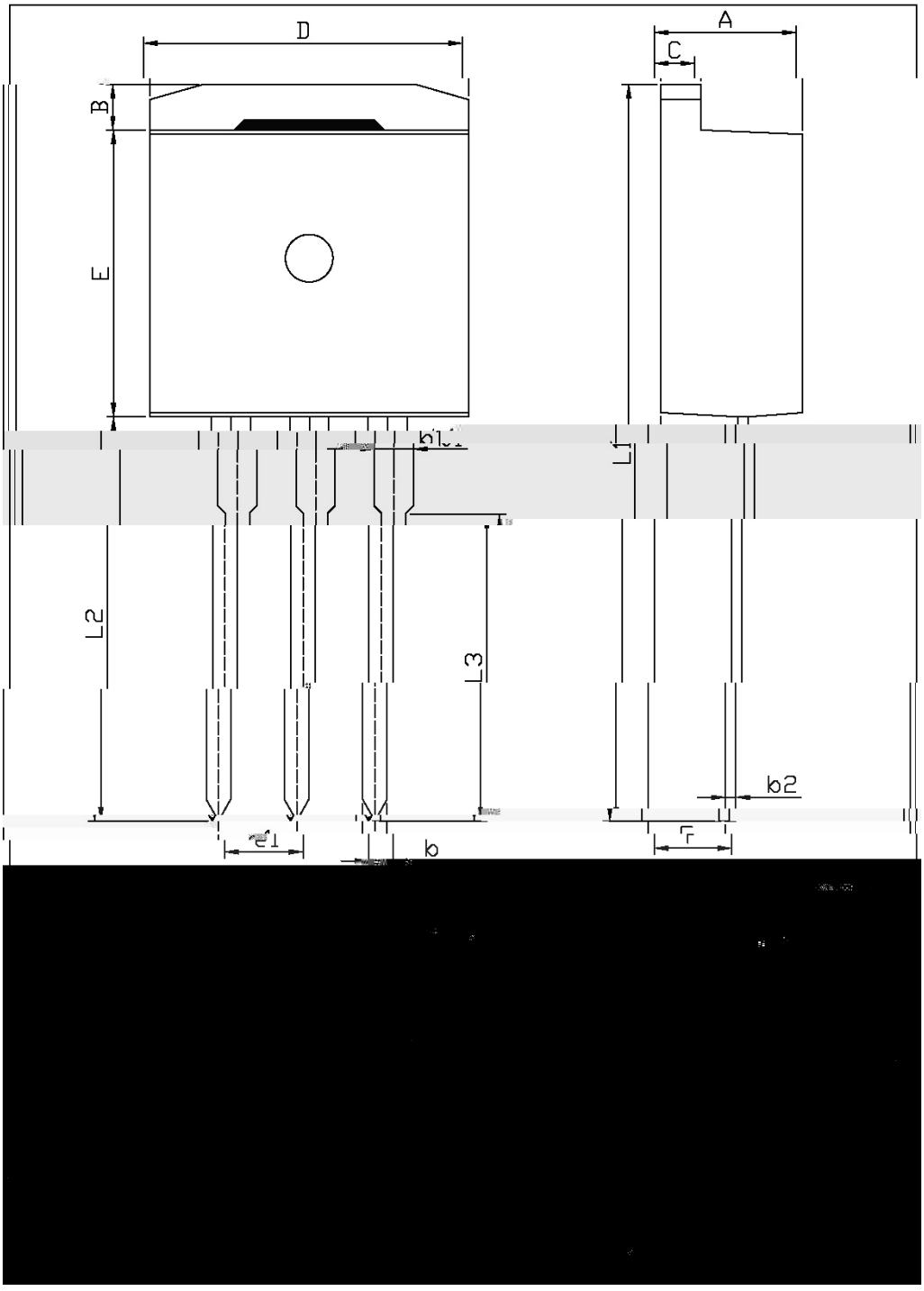




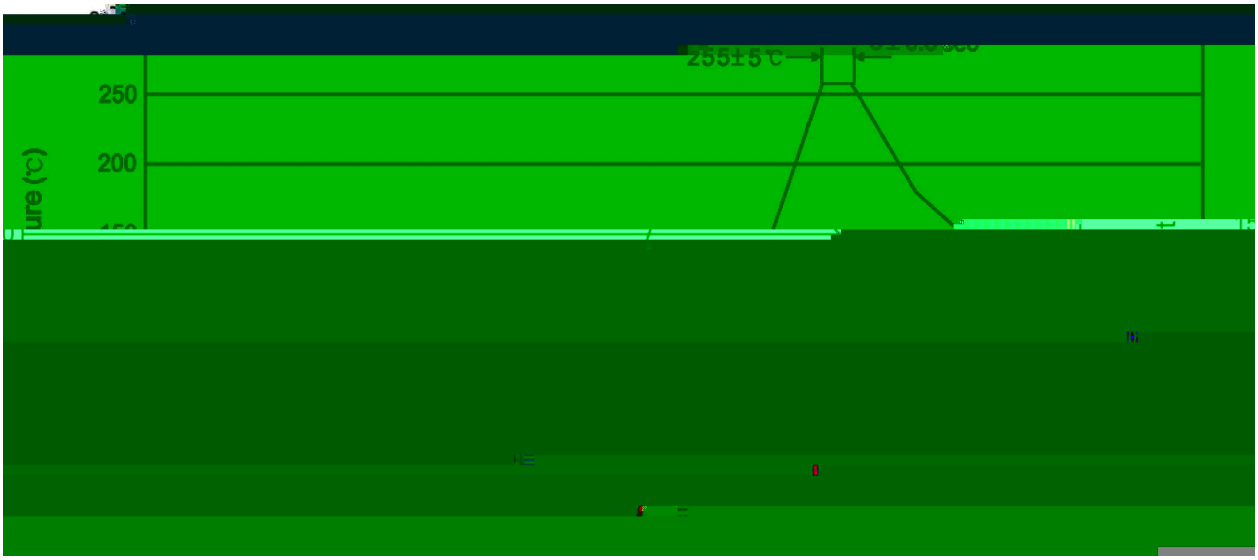
PIN1 G PIN 2 D PIN 3 S

Parameter	Symbol	Rating	Unit

/ Package Dimensions



( ) / Temperature Profile for Dip Soldering(Pb-Free)



			Note:	
1	25 150	60 90sec;	1.Preheating:25~150	, Time:60~90sec.
2	255±5	5±0.5sec;	2.Peak Temp.:255±5	, Duration:5±0.5sec.
3	2 10 /sec.		3. Cooling Speed: 2~10 /sec.	

/ Resistance to Soldering Heat Test Conditions

270±5	10±1 sec.	Temp.:270±5	Time:10±1 sec

/ Packaging SPEC.

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-262	50	20	1,000	5	5,000	532×31.4×5.5	555×164×50	575×290×180

/ Notices